

MURF620

Technical Data Data Sheet N0342, Rev. - **Green Products** 

## **MURF620 ULTRAFAST PLASTIC RECTIFIER**

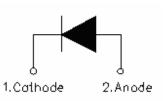
### Applications:

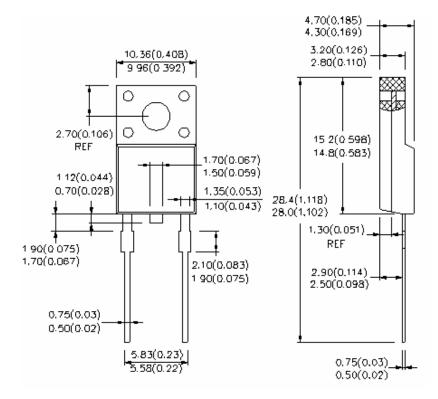
- Switching Power Supply
- Power Switching Circuits
- General Purpose

#### Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In Inches / mm





ITO-220AC

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



### **MURF620**

#### Technical Data Data Sheet N0342, Rev. -

#### **Green Products**





Where XXXXX is YYWWL

MUR	= Device Type
F	= Package type
6	= Forward Current (6A)
20	= Reverse Voltage (200V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions:	Molding resin
	Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping
MURF620	ITO-220AC (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	200	V
Max. Average Forward	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	6	A
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	60	A

 SMC SANGDEST MICROELECTRONICS

**MURF620** 

Technical Data Data Sheet N0342, Rev. - **Green Products** 

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V <sub>F1</sub>	@ 6A, Pulse, T <sub>J</sub> = 25°C	1.2	V
	V <sub>F2</sub>	@ 6A, Pulse, T <sub>J</sub> = 100°C	1.0	V
Max. Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 25°C	6	μA
	I <sub>R2</sub>	@V <sub>R</sub> = 0.8 V <sub>R</sub> T <sub>J</sub> = 100°C	60	μA
Max. Reverse Recovery Time	t <sub>rr</sub>	$I_F$ =500mA, $I_R$ =1A,and $I_{rm}$ =250mA	35	ns
RSM Isolation Voltage (t=1.0 second,R.H.< = $30\%$ , T <sub>A</sub> = $25^{\circ}$ C)	V <sub>1so</sub>	Clip mouting, the epoxy body away from the heatsink edge by more than 0.110"along the lead direction.	4500	V
		Clip mouting, the epoxy body is inside the heatsink	3500	
		Screw mounting, the epoxy body is inside the heatsink	1500	

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	8.0	°C/W
Approximate Weight	wt	-	1.6	g
Case Style		ITO-220AC		

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907
FAX (86) 25-87123900
World Wide Web Site - http://www.sangdest.com.cn
E-Mail Address - sales@ sangdest.com.cn



# MICROELECTRONICS

## **MURF620**

#### Technical Data Data Sheet N0342, Rev. -

#### **Green Products**

#### DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

<sup>4</sup>- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.